# **EPISTAR**

### **ES-SAHRPN08**

AlGaInP PN-series LED Chip

## > Mechanical Specification:

#### (1) Dimension

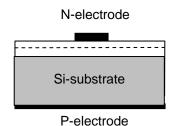
- Chip size: 8 mil x 8 mil (190±25 μm x 190±25 μm)

- Thickness: 6.7 mil (170±25  $\mu$ m) - N bonding pad: 3.5 mil (90±10  $\mu$ m)

#### (2) Metallization

Topside N electrode: Au alloyBackside P electrode: Au alloy





#### **Features:**

- · High luminous intensity
- · Thin film structure
- · Vertical electrode
- · High driving current

#### **Applications:**

- Backlighting
- · Signage and channel letter
- · Portable light source
- · Decorating lighting

# > Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward Voltage	Vf1		If = 10μA	1.3	-	-	V
	Vf2		If = 20mA	-	2.1	2.5	V
Reverse Current	Ir		Vr = 10V	-	-	5.0	μΑ
Peak Wavelength	λр		If = 20mA	-	631	-	nm
Dominant Wavelength <sup>(1)</sup>	λd		If = 20mA	619	624	629	nm
Spectra Half-width	Δλ		If = 20mA	-	20	-	nm
Luminous Intensity <sup>(2)(3)</sup>	lv	E12	If = 20mA	300	-	-	mcd
		E13		350	-	-	
		E14		400	-	-	

Note:

<sup>(1)</sup> Basically, the wavelength span is 10nm; however, customers' special requirements are also welcome.

<sup>(2)</sup> Customers' special requirements are also welcome.

<sup>(3)</sup> Luminous intensity is measured by EPISTAR's equipment on bare chips.

## > Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 40	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 10	V
Junction Temperature	Tj	-	≤ 115	°C
	Tstg	Chip	-40 ~ +85	°C
Storage Temperature		Chip-on-tape/storage	5~35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Printed Circuit Board (PCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

#### > Characteristic Curves:

Fig.1 – Relative luminous Intensity vs. Forward Current

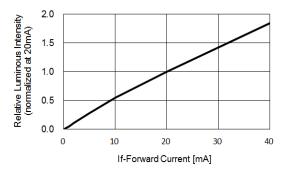


Fig.3 – Relative Intensity (@20mA) vs. Ambient Temperature

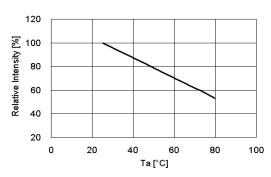


Fig.5 – Dominant Wavelength (@20mA) vs. Ambient Temperature

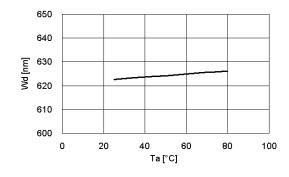


Fig.2 – Forward Current vs. Forward Voltage

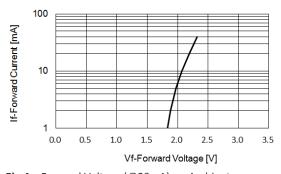


Fig.4 – Forward Voltage (@20mA) vs. Ambient Temperature

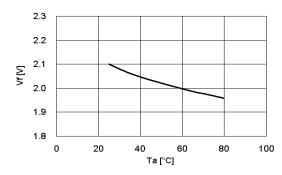


Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 115°C)

